

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No.: 10/007,631

Atty. Docket No.: S01-079

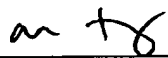
Filing Date: 11/09/2001

Art Unit: 2815

Applicants: Daniel S. Pickard et al.

Examiner: Joseph H. Nguyen

Title: ELECTRON BOMBARDMENT OF WIDE BANDGAP
SEMICONDUCTORS FOR GENERATING HIGH BRIGHTNESS AND
NARROW ENERGY SPREAD EMISSION ELECTRONS

CERTIFICATE OF MAILING	
I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450	
on <u>9/18/05</u> Date	Typed or printed name of person signing this certificate <u>Erica Hernandez</u>
	<u></u> Signature

REPLY UNDER 37 C.F.R. 1.111

Sir:

Applicant responds to the Office action mailed on 06/07/2005 as follows:

19/14/2005 SFELEKE1 00000016 10007631

11 FC:2231

60.00 OP

OK to enter JN 11/10/05

S01-079 (10/007,631)

1/8

Reply 2